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Designs and understanding of small moleculebased non-fullerene acceptors for realizing commercially viable organic photovoltaics

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Organic photovoltaics (OPVs) have emerged as a promising next-generation technology with great potential for portable, wearable, and transparent photovoltaic applications. Over the past few decades, remarkable advances have been made in non-fullerene acceptor (NFA)-based OPVs, with their power conversion efficiency exceeding 18%, which is close to the requirements for commercial realization. Novel molecular NFA designs have emerged and evolved in the progress of understanding the physical features of NFA-based OPVs in relation to their high performance, while there is room for further improvement. In this review, the molecular design of representative NFAs is described, and their blend characteristics are assessed *via* statistical comparisons. Meanwhile, the current understanding of photocurrent generation is reviewed along with the significant physical features observed in high-performance NFA-based OPVs, while the challenging issues and the strategic perspectives for the commercialization of OPV technology are also discussed.

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1. Introduction

The photovoltaic (PV) technology for converting sunlight into electricity is one of the sustainable solutions for overcoming the energy crisis and addressing climate change and is a rapidly growing field with increasing efficiencies. ^{1,2} While various other PV types are being actively developed, organic photovoltaic

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(OPV) technology is emerging as the next-generation PV technology with great potential for portable, flexible/stretchable, and transparent applications.³⁻⁷ With significant advances in material designs, film processing techniques, and device architectures,⁸⁻¹² the power conversion efficiency (PCE) of OPVs has reached around 18%, which is close to the requirements for commercialization.¹³⁻¹⁷

Two major breakthroughs in the history of OPV technology have significantly boosted device efficiency. While early-stage OPV devices adopted a single-component material for the photoactive layer and the PCE was only \sim 1%, the advent of the bulk-heterojunction (BHJ) system^{18–20} blended with an electron



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donor (D) and an acceptor (A) has allowed for improving the PCE by more than 10%, the first significant breakthrough in the OPV field.21,22 The BHJ system has demonstrated efficient photocurrent generation via increasing the D/A interfacial area and is widely adopted in most OPV devices. 18-20 Specifically, the BHJ blend OPVs consisting of a polymer donor and a fullerene acceptor (FA) (e.g., PC₆₁BM and PC₇₁BM) have received a great deal of attention, providing a comprehensive understanding of the photo-conversion process in the BHJ blend system as well as valuable insights into the design of high-performance OPVs. The PCE of FA-based binary blend OPVs has reached up to \sim 12% (ref. 23) through the development of numerous polymer donors (e.g., 11.7% for PffBT4T-C₉C₁₃:PC₇₁BM); however, further improvements have been hindered by various critical drawbacks, including narrow and weak light absorption, large voltage loss, and thermal and/or photo-chemical instability.24-26 Meanwhile, chemically modifiable non-fullerene acceptors (NFAs) have emerged as an alternative to FAs for overcoming the aforementioned optical and photophysical issues.8,27-35 In practice, employing an NFA as a host acceptor in binary blends17,24,31,36 or as a secondary acceptor in ternary blends37-41 has proven to exceed the theoretical efficiency (~15%) of FAbased OPVs, 42 which presents the second major breakthrough in OPV technology. As the molecular design of NFAs continues

to evolve, NFA-based binary blend OPVs have recently demonstrated a high PCE of over 18%, 15,17 indicating their potential for meeting the commercial requirements (e.g., 18-22% for silicon solar cells). Moreover, NFA-based OPVs have the technological capacity for wearable and transparent PV applications owing to their excellent mechanical stability4 and near-infrared (NIR) light absorption.6,7,43-48

The distinctive features of NFA-based OPVs become clear following statistical comparisons with FA-based OPVs (Fig. 1). One significant feature of NFA-based OPVs is the high shortcircuit current density (I_{SC}) with a small optical bandgap (E_g) , i.e., the smaller optical bandgap of the donor or acceptor (Fig. 1a and b). In fact, FA-based OPVs have a E_g distribution concentrated at 1.5–1.8 eV, with the $J_{\rm SC}$ being less than 20 mA cm⁻². Meanwhile, in terms of NFA-based OPVs, the E_g is mainly distributed in the 1.2-1.6 eV range, while they exhibit a higher $J_{\rm SC}$ (>20 mA cm⁻²) than FA-based OPVs at $E_{\rm g}$ < 1.5 eV. The other important feature is the low voltage loss (V_{loss}) with a small energy offset (Fig. 1c-f), where the energy offset defines the lowest unoccupied molecular orbital (LUMO) offset (ΔE_{LUMO}) or the highest occupied molecular orbital (HOMO) offset (ΔE_{HOMO}). Here, while FA-based OPVs have a V_{loss} of 0.6–1.2 V at a ΔE_{HOMO} or ΔE_{LUMO} of <1.0 eV, NFA-based OPVs exhibit a lower $V_{\rm loss}$ (<0.8 V) in the same offset region. In fact, comparatively low

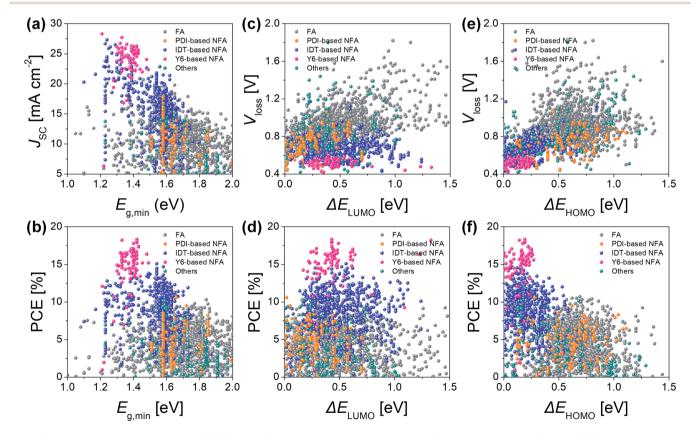


Fig. 1 Statistical data collected from ≈ 2000 pairs of FA- and NFA-based binary blend OPVs over the last 10 years. (a) Short-circuit current density (J_{SC}) and (b) power conversion efficiency (PCE) versus $E_{a,min}$. (c) Voltage loss (V_{loss}) and (d) PCE versus the lowest unoccupied molecular orbital (LUMO) offset (ΔE_{LUMO}). (e) V_{loss} and (f) PCE versus the highest occupied molecular orbital (HOMO) offset (ΔE_{HOMO}). The each color means data of polymer donor:FA (grey dots), polymer donor:PDI-based NFA (orange dots), polymer donor:IDT-based NFA (navy dots), polymer donor:Y6-based NFA (pink dots) and polymer donor:others (NFAs which are not included in PDI, IDT, and Y6 categories) (green dots).

 $V_{\rm loss}$ (\approx 0.5 V) values can be observed in many NFA-based OPVs with a $\Delta E_{\rm HOMO}$ of <0.3 eV. These statistical comparisons indicate that NFA-based OPVs generate a photocurrent with different operating mechanisms compared with FA-based OPVs; however, the origin of the significant improvements in the performance of NFA-based OPVs has, as yet, not been fully understood. In addition to the features of $E_{\rm g}$ and energy offset (*i.e.*, $\Delta E_{\rm LUMO}$ and $\Delta E_{\rm HOMO}$), various updated materials and physical discoveries related to NFA-based OPVs are being regularly reported, thus providing a better fundamental understanding for designing high-performance OPVs.

In this review, we first cover the existing knowledge regarding the operating principles of OPVs (Section 2) and describe the molecular designs of representative NFAs in relation to the statistically collected PV parameters (Section 3). Following this, we review the current understanding and the significant features observed in NFA-based OPVs, with a specific focus on the photophysical, electrical, and morphological characteristics (Section 4). Finally, we provide a concise summary and discuss the various perspectives on realizing high-performance and functional OPVs for technological commercialization (Section 5).

2. OPV operation

The OPV operation involves photocurrent generation *via* a sequential process in the BHJ active layer (Fig. 2), 20,26,49,50 which consists of the following stages: (1) Frenkel excitons (*i.e.*, tightly bound electron–hole pairs) are formed following light absorption, (2) the excitons diffuse to the D/A interfaces and form charge transfer (CT) excitons (*i.e.*, weakly bound electronhole pairs), (3) the CT excitons are dissociated into free charge carriers by the built-in potential in devices, (4) the free charges transport to each electrode (*i.e.*, holes to anode, electrons to cathode), and (5) the charges are collected at the electrodes, thus generating an electric current. The overall efficiency (η) of photocurrent generation is defined as follows:

$$\eta = \eta_{\rm abs} \eta_{\rm ed} \eta_{\rm CT} \eta_{\rm CC} \tag{1}$$

where $\eta_{\rm abs}$, $\eta_{\rm ed}$, $\eta_{\rm CT}$, and $\eta_{\rm CC}$ are the efficiency of photon absorption, exciton diffusion, CT exciton dissociation, and charge collection, respectively. Here, $\eta_{\rm abs}$ is affected by the

range and intensity of the light absorption, while $\eta_{\rm CT}$ is highly associated with the energy offset between $E_{\rm g}$ and the energy of the CT state ($E_{\rm CT}$). Meanwhile, the $\eta_{\rm ed}$ and $\eta_{\rm CC}$ are greatly influenced by the blend morphology and charge carrier mobility of the materials.

In practice, the PV characteristics of OPVs are evaluated in terms of current–voltage (I-V) measurements, where the output current is obtained at each step of an applied voltage under solar illumination. The efficiency in converting sunlight to electricity (*i.e.*, PCE) is estimated from the measured I-V curve and is defined as follows: 51,52

$$PCE = \frac{J_{SC} \times V_{OC} \times FF}{P_{in}}$$
 (2)

where $P_{\rm in}$ is the intensity of the incident sunlight under AM 1.5G ($P_{\rm in}=100~{\rm mW~cm^{-2}}$ at the AM 1.5G condition) and $J_{\rm SC}$, opencircuit voltage ($V_{\rm OC}$), and fill factor (FF) are the main PV parameters for determining the PCE of the device. The parameters $J_{\rm SC}$, $V_{\rm OC}$, and FF are closely related to each other and are influenced by various factors, including the material, the blend system, the morphology, and the device architecture. As such, the underlying origin of the three parameters has not yet been fully established, and numerous relevant studies are actively underway (see Section 4).

Molecular designs of NFAs

Among the various NFAs, three types of molecular design, perylenediimide (PDI)-based, indacenodithiophene (IDT)-based, and Y6-based, have demonstrated outstanding PV performances (see Fig. 1).^{32,36,53} In this section, we describe the molecular design for these three types of NFA in terms of the optoelectronic and structural properties required for high-performance OPVs, while the device characteristics observed in various blend systems are also discussed (the chemical structures of polymer donors, FAs, PDI-based NFAs, IDT-based NFAs, and Y6-based NFAs are shown in Fig. 3, and OPV performance of representative FA- and NFAbased OPVs is shown in Table 1).

3.1. PDI-based NFAs

The PDI unit has a large planar structure with tetracarboxylic diimide groups, which means PDI-based molecules have strong

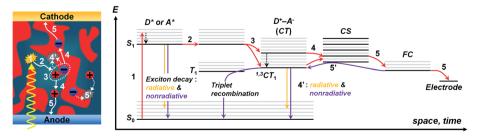


Fig. 2 Illustration of OPV operation according to a sequential process: (1) light absorption and exciton generation, (2) exciton diffusion, (3) charge separation, (4) charge transport, (4') geminate recombination, (5) charge collection, (5') non-geminate recombination (left), excited-state Jablonski diagram for description of charge generation and recombination processes in OPVs based on the BHJ active layer (S_0 : ground state; S_1 : the lowest singlet state; T_1 : the lowest triplet state; CT: charge transfer state; CS: charge separation state; FC: free charge carrier) (right).

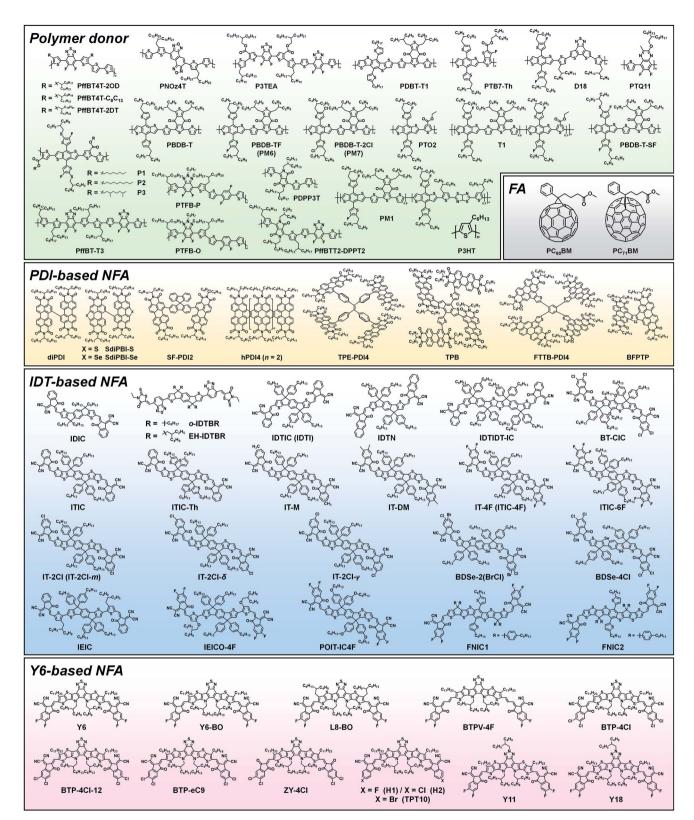


Fig. 3 Chemical structures of polymer donors, FAs, and NFAs (PDI-based NFA, IDT-based NFA, and Y6-based NFA) discussed in this review.

intermolecular interaction and high electron affinity (LUMO ≈ -3.8 eV).32,54 Hence, PDI-based molecules are currently employed as electron-accepting54-57 and/or transporting materials57-60 in organic electronic devices. However, the self-

aggregation induced by the strong intermolecular interactions among the PDI units lowers the solubility in common solvents and forms particularly large domains in BHJ blends, thus limiting the exciton dissociation and diffusion.32,61,62 The

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Table 1 OPV performance of representative polymer donor:FA and polymer donor:NFA blend photoactive layers

Acceptor	Donor	$V_{\mathrm{OC}}\left[\mathbf{V}\right]$	$J_{ m SC}[{ m mA~cm}^{-2}]$	FF [%]	PCE [%]	$V_{ m loss}\left[m V ight]$	Ref.
FAs							
PC ₇₁ BM	PffBT4T-C ₉ C ₁₃	0.78	19.8	73	11.7	0.87	23
$PC_{71}BM$	PffBT4T-2OD	0.77	18.4	74	10.5	0.88	22
PC ₇₁ BM	PNOz4T	0.96	14.5	64	8.9	0.56	74
PDI-based NFAs							
SdiPBI-S	PDBT-T1	0.90	11.7	66	7.2	0.95	66
SdiPBI-Se	PDBT-T1	0.95	12.5	70	8.4	0.90	67
SF-PDI2	P3TEA	1.11	13.3	64	9.5	0.61	69
hPDI4	PTB7-Th	0.80	15.2	68	8.3	0.78	64
TPB	PTB7-Th	0.79	17.9	58	8.5	0.79	70
FTTB-PDI4	P3TEA	1.13	13.9	66	10.6	0.53	72
IDT-based NFAs							
IT-4F	T1	0.90	21.5	78	15.1	0.64	75
IT-4F	PTO2	0.91	21.5	75	14.7	0.67	76
IT-4F	PBDB-T-SF	0.88	20.9	71	13.1	0.66	77
BDSe-4Cl	PM7	0.83	22.5	74	13.8	0.56	78
BDSe-2(BrCl)	PM7	0.83	22.9	77	14.5	0.56	78
POIT-IC4F	PM6	0.91	20.9	73	13.8	0.58	79
Y6-based NFAs							
Y6	D18	0.86	27.7	77	18.2	0.47	15
Y6-BO	PM6	0.86	25.3	76	16.4	0.48	80
L8-BO	PM6	0.87	25.7	82	18.3	0.55	17
BTP-4Cl-12	PM6	0.86	25.6	78	17.0	0.53	81
BTP-eC9	PM6	0.84	26.2	81	17.8	0.56	16
Y11	PM6	0.83	26.7	74	16.5	0.48	82

molecular design of PDI-based materials appears to suppress the self-aggregation through structural torsion⁶³ or ring fusion.64 Here, the structure of PDI dimers or tetramers linked through C-C single bonds⁶⁵⁻⁶⁷ or π -conjugated units⁶⁸⁻⁷¹ (e.g., spirofluorene and benzene) exhibit highly twisted conformation with torsional angles of 40°-80°, which effectively inhibits the self-aggregation in blend films. Nonetheless, low device performance remains an issue in twisted PDI-based blend OPVs because of their low electron mobility (μ_e) and narrow light absorption (400-600 nm). Here, the ring fusion of PDI-based NFAs can lower the torsional angles between the units $(\approx 25^{\circ})$, ⁶⁴ resulting in closer intermolecular packing than that in PDI dimers and tetramers. These structural features have been reported to be effective in improving the μ_e ($\approx 10^{-3}$ cm² V⁻¹ s⁻¹) without generating large domains in blend films. For example, ring fusion to PDI tetramer (FTTB-PDI4)72,73 builds a "doubledecker" geometry, where adjacent PDI units exhibit close to parallel conformation for close intermolecular packing.

The high-performance blend system of PDI-based NFAs and polymer donors ($E_{\rm g}\approx 1.6$ eV) exhibits a light absorption in the 300–800 nm range and a $J_{\rm SC}$ of 15–20 mA cm⁻², which is similar to FA-based OPVs (Fig. 1a). Meanwhile, the $V_{\rm loss}$ of PDI-based OPVs is mainly distributed in the 0.6–0.8 V range at a $\Delta E_{\rm LUMO}$ of <0.5 eV, and is around 0.4 V smaller than that of FA-based OPVs (Fig. 1c).

3.2. IDT-based NFAs

The IDT unit, a pentacyclic ladder-type arene, has a five-fused aromatic structure with high planarity and strong rigidity.^{83,84}

The molecular design of IDT-based NFAs has evolved through chemical modifications of the backbone, side chains, and end-groups. 32,89 Increasing the number of fused rings or inserting additional electron-donating units has proven to be effective in reducing the $E_{\rm g}$ of IDT-based NFAs through extending the conjugation length. $^{44,90-92}$ The bulky side chains on the sp 3 -hybridized carbon (C) atoms of the IDT unit play an important role in determining the solubility of IDT-based NFAs, but cause some steric hindrance among the IDT units. Hence, for the most part, IDT-based NFAs have a linear stacked packing structure formed through end-group π – π stacking, 36,93 and the modification of the alkyl side chains (e.g., shape, length, and branch position) has been exploited to modulate the intermolecular interactions and the blend miscibility with the polymer donors. 94,95 Chemically substituting hydrogen (H) atoms of the

end-group with strong electronegative atoms (e.g., fluorine [F] and chlorine [Cl]) has also proven to be an effective molecular design strategy for improving the μ_e ($\approx 10^{-4}$ cm² V⁻¹ s⁻¹) of IDT-based NFAs through enhancing the intermolecular interactions.77,96-98

The blend system of IDT-based NFAs and polymer donors (e.g., PBDB-T analogs, PTB7-Th) covers the light absorption in the range of 400–1000 nm, and IDT-based devices with an E_{α} of <1.5 eV tend to exhibit a high J_{SC} of >20 mA cm⁻² (Fig. 1a). Specifically, the PTB7-Th:IEICO-4F device99 achieves the highest $J_{\rm SC}$ of 27.3 mA cm⁻² among all the IDT-based blend OPVs. The $V_{\rm loss}$ of IDT-based blends tends to be sensitive to the $\Delta E_{\rm HOMO}$ and has a narrow distribution of 0.4-0.8 V at a ΔE_{HOMO} of <0.5 eV (Fig. 1e).

3.3. Y6-based NFAs

Unlike IDT-based NFAs, the molecular design feature of Y6based NFAs revolves around the adoption of an electrondeficient polycyclic arene as a core unit, in which benzothiadiazole and dithienothiophene[3,2-b]-pyrrolo are fused (i.e., D-A'-D-type structure).7,100-102 With two end-groups linked to the core unit (i.e., A-D-A'-D-A structure), Y6-based NFAs exhibit a crescent shape and an axisymmetric structure. 100,101 The A-D-A'-D-A structure in Y6-based NFAs enables a smaller E_{g} (1.2-1.4 eV) than do IDT-based NFAs through a strong ICT effect, absorbing light with an onset of 900-1100 nm. Another feature of Y6-based NFAs is the multiple packing between the core units or end-groups, 103,104 since the alkyl side chains are attached to the sp²-hybridized nitrogen (N) atoms of the core unit, less bulky than the sp³-hybridized C atoms (i.e., one alkyl chain per N atom and two alkyl chains per C atom). The multiple packing results in the efficient electron transport of Y6-based NFAs with a μ_e of $\approx 10^{-4}$ cm² V⁻¹ s⁻¹. 101,103,104

Similar to IDT-based NFAs, the molecular modification of Y6-based NFAs has been focused on the electronic and structure properties. The extension of the fused-ring core and the insertion of a π -linker have been the main approaches in terms of backbone modification in view of increasing the effective conjugation length of Y6-based NFAs (i.e., smaller $E_{\rm g}$), $^{105-107}$ while modifications of the alkyl side chains have also been employed to control the intermolecular packing and solubility in this type of NFA.16,17,80,108 Interestingly, it has recently been demonstrated that the alkyl side chains adjacent to the endgroups prevent the rotating end-groups (i.e., conformational locking), thereby lowering the energetic disorders to improve the charge transport.109,110 Meanwhile, the end-group of Y6based NFAs has largely been modified through chemical substitutions using electronegative atoms (e.g., F and Cl) to control the LUMO levels and molecular packing, much like in IDT-based NFAs. 101,111,112

The Y6-based blend system exhibits a complementary light absorption of 400–1100 nm with polymer donors (e.g., PBDB-T analogs or PTB7-Th). The Y6-based devices with an $E_{\rm g}$ of <1.4 eV attain a high J_{SC} of >23 mA cm⁻² (Fig. 1a). The V_{loss} of the Y6-based blends is distributed in the 0.4-0.6 V range with an average of 0.52 V at a ΔE_{HOMO} of <0.3 eV, which is much lower

than those of the other two types of NFA-based OPV (Fig. 1e). A significant number of Y6-based blends have exhibited excellent device performance, with a PCE of 15-18%, while most recently, the highest PCE of 18.32% has been reported in a Y6 analogbased device (PBDB-TF:L8-BO).17

Key physical features in NFA-based **OPVs**

The increase in the $J_{\rm SC}$ and $V_{\rm OC}$ of NFA-based OPVs can be largely attributed to the specific molecular design of the NFA, which creates distinctive physical features that differ from those of FA-based OPVs. In this section, we describe the physical features observed in NFA-based OPVs in relation to those of FAbased OPVs and review the current understanding of their fundamental aspects in terms of light harvesting, voltage loss, charge transport, triplet-exciton utilization, and blend morphology.

4.1. Light harvesting

4.1.1. Photon absorption. The degree of conversion from sunlight (i.e., incident photon) to electrical current is described in terms of the external quantum efficiency (EQE), which is defined as follows:49

$$EQE = \eta_{abs}IQE \tag{3}$$

The internal quantum efficiency (IQE) is the ratio of the number of charge carriers collected by the device to the number of photons from the device (i.e., photons absorbed by the device). The J_{SC} , one of the main PV parameters, is expressed as follows:49

$$J_{\text{SC}} = q \int_{E_{\sigma}}^{\infty} \text{EQE}(E) \mathcal{O}_{\text{AM1.5G}}(E) dE$$
 (4)

where q, E, and $\emptyset_{AM1.5G}$ are the elementary charge, photon energy, and air mass (AM) 1.5G solar spectrum, respectively. The EQE(E) under the Shockley–Queisser (SQ) limit is expressed as an ideal step-like function: 49,113

$$EQE = \begin{bmatrix} 100\% & E \ge E_{g} \\ 0 & E < E_{g} \end{bmatrix}$$
 (5)

In theory, when photons with $E \ge E_g$ are absorbed, they are completely converted to electricity, and the $J_{\rm SC}$ can be maximized to $J_{SC,SO}$ (Fig. 4a).

$$J_{\text{SC,SQ}} = q \int_{E_g}^{\infty} \mathscr{O}_{\text{AM1.5G}}(E) dE$$
 (6)

In addition, the solar irradiance in the range of 400-800 nm is over 1.0 W m⁻² nm⁻¹ (Fig. 4b), indicating that a large number of photons are provided in this region. Therefore, a desirable D/ A blend should have a strong absorption coefficient (α) while absorbing visible and NIR regions (>400 nm).

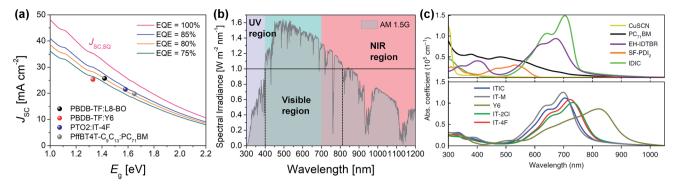


Fig. 4 (a) Calculated J_{SC} as a function of E_g according to the external quantum efficiency (EQE) assumed to be a constant value above the E_g . J_{SC} of representative FA- and NFA-based OPVs (*i.e.*, PBDB-TF:L8-BO,¹⁷ PBDB-TF:Y6,¹⁰¹ PTO2:IT-4F,⁷⁶ and PffBT4T- C_9C_{13} :PC $_{71}$ BM²³). (b) Solar spectrum under AM 1.5G; purple (\leq 400 nm), green (400–700 nm), and red (\geq 700 nm) area mean UV, visible, and near-infrared (NIR) region, respectively. Black solid line represents spectral irradiance of 1.0 W m⁻² nm⁻¹ and black dotted lines provide the region over spectral irradiance of 1.0 W m⁻² nm⁻¹ (400–800 nm). (c) Absorption coefficient (α) of PC $_{71}$ BM and NFAs (EH-IDTBR, SF-PDI2, IDIC, ITIC, IT-M, Y6, IT-2Cl, and IT-4F). Reproduced with permission.¹¹⁶ Copyright 2020, Springer Nature.

Conventional FAs (e.g., PC₆₁BM or PC₇₁BM) exhibit a relatively short absorption range of 300–500 nm with weak α values; 114 hence, the light harvesting of FA-based OPVs is largely determined by the absorption of polymer donors. For example, the PffBT4T-C₉C₁₃:PC₇₁BM blend OPV absorbs up to 750 nm of light and exhibits a $J_{\rm SC}$ of 19.8 mA cm $^{-2}$. 23 Meanwhile, the complementary absorption of medium- $E_{\rm g}$ polymer donors and narrow- $E_{\rm g}$ NFAs covers a wide range of light absorption, enabling a high $J_{\rm SC}$ of >20 mA cm $^{-2}$. This is also related to the extinction coefficient (k), an optical constant for how strongly a material absorbs light at a specific wavelength ($\alpha=4\pi k/\lambda$, λ is wavelength). 115 Most NFAs have higher α and k values (α > 1.0 × 10^5 cm $^{-1}$; k > 1.0) than PC₇₁BM ($\alpha\approx0.9\times10^5$ cm $^{-1}$; $k\approx0.4$) in the region from visible to NIR (Fig. 4c). 115,116

The approach to designing D-A-type conjugated molecules is effective in terms of adjusting the E_g via the ICT effect and provides variable light absorption. Furthermore, the more planar the molecular backbone, the stronger the ICT effect. In recent years, it has been demonstrated that the molecular design of an A-D-A-type NFA is effective in terms of NIR light absorption because of its high planarity and the strong electronwithdrawing ability of the A units (e.g., $E_g = 1.59$, 1.51, and 1.24 eV for ITIC, IT-4F, and IEICO-4F, respectively).77,117-119 The crescent-shaped A-D-A'-D-A-type structure (Y6 analogs) has also demonstrated an effective design approach to NIR light absorption >900 nm (e.g., $\underline{E}_{g} = 1.33$ eV for Y6 and $\underline{E}_{g} = 1.21$ eV for BTPV-4F),101,107 while devices with Y6 analogs exhibit a high $J_{\rm SC}$ of >23 mA cm⁻², which is comparable to that of perovskite solar cells (e.g., 27.7 mA cm^{-2} for D18:Y6 (ref. 15) and 28.3 mA cm^{-2} for PTB7-Th:BTPV-4F¹⁰⁷).

4.1.2. Exciton diffusion. The photoactive layer thickness is another important factor in efficient light harvesting. 120,121 The photogenerated excitons diffuse to the D/A interface before decaying to a ground state; however, polymer donors and FAs typically have a short exciton diffusion length ($L_{\rm D}$) of 5–20 nm, 122,123 which limits the thick-film fabrication of >100 nm with a high $J_{\rm SC}$. Here, NFA-based OPVs exploit two photocurrent generation channels, exciton generation from the donor

(channel-I) and the acceptor (channel-II), while FA-based OPVs operate predominantly on channel-I.20 Therefore, NFAs with a long $L_{\rm D}$ s can greatly improve the photocurrent generation through channel-II. 124,125 Firdaus et al. performed EQE measurement of CuSCN/NFA (60-100 nm) bilayer devices and found that representative NFAs (i.e., SF-PDI2, EH-IDTBR, IDIC, ITIC, IT-M, IT-2Cl, IT-4F, and Y6) have a longer $L_{\rm D}$ s (20–47 nm) than typical polymer donors and FAs. 116 Subsequently, the exciton annihilation analysis using ultrafast transient spectroscopy revealed that NFAs have higher diffusion coefficients (D) than PC₇₁BM (e.g., $D = 0.064 \text{ cm}^2 \text{ s}^{-1}$ for IT-4F and D = $0.00016 \text{ cm}^2 \text{ s}^{-1}$ for PC₇₁BM). Meanwhile, quantum chemical calculations for NFAs have revealed that planar and stiff conjugated A-D-A (or A-D-A'-D-A) structures form close molecular packing and reduce the energetic disorder, resulting in a long $L_{\rm D}$ s. Recently, Ma et al. reported a $\sim 1~\mu {\rm m}$ thick active layer device (PBDB-TF:BTP-4Cl-12) with a high J_{SC} of 27.3 mA cm^{-2} . 126

4.2. Voltage loss

4.2.1. Energy loss in the CT state. The excitons in organic materials (*i.e.*, Frenkel excitons) have a large binding energy ($E_{\rm b}$) of 0.2–1.5 eV because of their low permittivity ($\varepsilon_{\rm r} \approx 3$ –4).¹²⁷ However, the CT excitons at the D/A interface have a lower $E_{\rm b}$ of 0.3–0.5 eV,^{128,129} promoting efficient exciton dissociation into free charges. The $E_{\rm CT}$ is given by the following:¹²⁹

$$E_{\rm CT} = |\rm HOMO_D - LUMO_A| - E_b \tag{7}$$

where $\mathrm{HOMO_D}$ is the HOMO of the donor and $\mathrm{LUMO_A}$ is the LUMO of the acceptor. Despite the benefits of exciton splitting, CT excitons are the source of substantial V_{loss} . Here, the V_{loss} can be expressed as follows:¹³⁰

$$V_{\text{loss}} = E_{\text{g}}/q - V_{\text{OC}} = (E_{\text{g}}/q - E_{\text{CT}}/q) + (E_{\text{CT}}/q - V_{\text{OC}}) = \Delta E_{\text{CT}}/q + \Delta V_{\text{rec}}$$
 (8)

where $\Delta E_{\rm CT}$ ($\Delta E_{\rm CT} = E_{\rm g} - E_{\rm CT}$) and $\Delta V_{\rm rec}$ are the energy offset and the V_{loss} incurred via recombination, respectively, which are prominently observed in blend OPVs. While the $\Delta E_{\rm CT}$ is the driving force for charge-separation, it presents an inevitable $V_{\rm loss}$ because the $E_{\rm CT}$ lies below the lowest excited state (S₁) of the donor or acceptor. Thus, the $\Delta E_{\rm CT}$ should be as small as possible to minimize the $V_{\rm loss}$. Meanwhile, the $\Delta V_{\rm rec}$ term can be divided into radiative recombination ($\Delta V_{\rm OC}^{\rm rad}$) and non-radiative recombination ($\Delta V_{\mathrm{OC}}^{\mathrm{non-rad}}$). Most blend OPVs exhibit low luminescence and possess a large $\Delta V_{\rm OC}^{\rm non-rad}$ (0.4–0.5 eV). 130–132 Therefore, $\Delta V_{\rm OC}^{\rm non-rad}$ is the main loss in $\Delta V_{\rm rec}$ and can be expressed as follows:129,130,132

$$\Delta V_{\rm OC}^{\rm non-rad} = -\frac{k_{\rm b}T}{q} \ln({\rm EQE_{EL}}) \approx -\frac{k_{\rm b}T}{q} \ln\left(\frac{k_{\rm r}}{k_{\rm r} + k_{\rm nr}}\right) \quad (9)$$

where $k_{\rm b}$, T, EQE_{EL}, $k_{\rm r}$, and $k_{\rm nr}$ are the Boltzmann constant, the temperature, the EQE of electroluminescence (EL), the radiative recombination rate, and the non-radiative recombination rate, respectively. Since the CT rate $(k_{\rm CT})$ competes with the nonradiative recombination channel (k_{nr}) , a higher k_{CT} is desirable to suppress the $\Delta V_{\rm OC}^{\rm non-rad}$.

4.2.2. Energy offset (ΔE_{CT}) . Understanding the physical relationship between the $\Delta E_{\rm CT}$ and the $k_{\rm CT}$ can help in determining the optimal $\Delta E_{\rm CT}$ in BHJ blends. Here, Coffey et al. investigated the $k_{\rm CT}$ and $\Delta E_{\rm CT}$ for polymer donor:FA blends and found that the maximum $k_{\rm CT}$ was yielded at an $\Delta E_{\rm CT}$ of 0.4-0.8 eV.¹³³ Elsewhere, Liu et al. reported that polymer donor:NFA blends exhibited the maximum $k_{\rm CT}$ even at a low $\Delta E_{\rm CT}$ (≈ 0.2 eV).134 Meanwhile, various theoretical studies based on the Marcus-Jortner electron transfer theory have described how a low intramolecular (λ_I) and intermolecular reorganization energy ($\lambda_{\rm O}$) can yield a maximum $k_{\rm CT}$ even with a small $\Delta E_{\rm CT}$ (Fig. 5a).129,134

In terms of molecular structure, increasing the planarity and/or the effective conjugation length of the molecular backbone has proven to be effective in reducing the λ_I . Most NFAs have a lower $\lambda_{\rm I}$ (e.g., $\lambda_{\rm I}=0.179,\ 0.101,\ {\rm and}\ 0.157$ for IDT-IC, IDTIDT-IC, and BT-CIC, respectively) than FAs (e.g., $\lambda_{\rm I} = 0.180$ for PC₇₁BM).¹³⁴ The molecular reorientation (i.e., intermolecular reorganization) occurs at the D/A interface during the CT process, changing the charge distribution of the donor and the acceptor. In this regard, the electronic polarization, or the dielectric response, influences the λ_0 in CT exciton splitting, which can be simplified in terms of the spherical cavity model established by Marcus:134-136

$$\lambda_{\rm O} = \frac{e^2}{4\pi\varepsilon_0} \left(\frac{1}{\varepsilon_{\rm opt}} - \frac{1}{\varepsilon_{\rm r}} \right) \left(\frac{1}{2r_{\rm D}} + \frac{1}{2r_{\rm A}} - \frac{1}{R_{\rm DA}} \right) \tag{10}$$

where e, ε_0 , $\varepsilon_{\rm opt}$, $\varepsilon_{\rm r}$, $r_{\rm D(A)}$, and $R_{\rm DA}$ are the elementary charge, the vacuum permittivity, the optical and relative dielectric

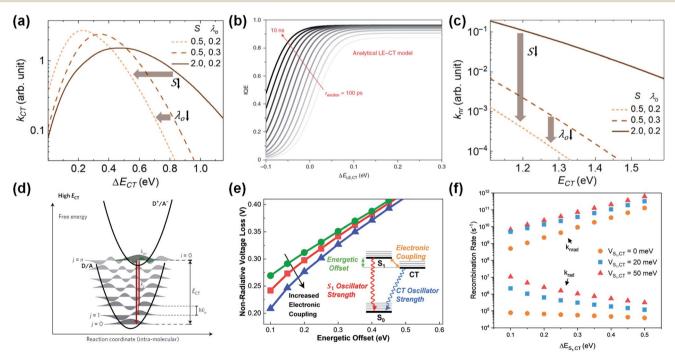


Fig. 5 (a) CT rate (k_{CT}) versus energy offset (ΔE_{CT}) . The peak k_{CT} occurs as intermolecular reorganization energy (λ_0) and intramolecular coupling strength (S) decrease. S is correlated with intramolecular reorganization energy (λ_l) and is expressed as $S = \lambda_l/\hbar \langle \omega_l \rangle$. Reproduced with permission. 129 Copyright 2019, Elsevier. (b) Calculation of IQE (consistent with exciton-splitting efficiency) based on the energy difference between the lowest excited state (LE is consistent with S_1) and CT state ($\Delta E_{1F,CT}$), and exciton lifetime (τ_{exc}). Reproduced with permission.¹³⁹ Copyright 2020, Springer Nature. (c) Non-radiative CT recombination rate $(k_{\rm nr})$ versus $E_{\rm CT}$ as a function of $\lambda_{\rm O}$ and S. The $k_{\rm nr}$ decreases as $\lambda_{\rm O}$ and S decreases and ECT increases. Reproduced with permission. ¹²⁹ Copyright 2019, Elsevier Inc. (d) The potential energy of the ground state (D/A) and the CT state (D⁺/A⁻). Reproduced with permission. ¹³² Copyright 2017, Springer Nature. (e) Simulated non-radiative recombination voltage loss (ΔV^{non} $_{\odot}^{\rm rad}$ oc) versus $\Delta E_{\rm CT}$ as a function of electronic coupling (hybridization). Inset schematic diagram represents three-state model. (f) Recombination rate versus ΔE_{CT} as a function of hybridization. Reproduced with permission. ¹⁴¹ Copyright 2019, American Chemical Society.

constants, the donor (or acceptor) radius, and the distance between the center to center of the donor and the acceptor, respectively. Here, the $\varepsilon_{\rm opt}$ is extracted in terms of $\varepsilon_{\rm opt} = n^2$ ($n = {\rm refractive\ index}),^{137}$ while the $\varepsilon_{\rm r}$ is obtained according to the Clausius–Mossotti equation that comprises molecular polarizability (α) and molecular volume (V): ¹³⁸

$$\frac{\varepsilon_{\rm r} - 1}{\varepsilon_{\rm r} + 2} = \frac{4\pi}{3} \frac{\alpha}{V} \tag{11}$$

In short, a larger $\varepsilon_{\mathrm{opt}}$ and ε_{r} and a smaller R_{DA} can lead to a lower λ_{O} in the CT state. Furthermore, a large ε_{r} and an average electron–hole distance (r) will reduce the E_{b} , resulting in a small ΔE_{CT} . The E_{b} can be expressed as follows:¹³⁸

$$E_{\rm b} \approx \frac{e^2}{4\pi\varepsilon_0\varepsilon_{\rm r}r}\tag{12}$$

The difference in the n of acceptor materials was reported by Kerremans et~al., with the ellipsometry measurement revealing higher n values (i.e., $\varepsilon_{\rm opt}$) in NFAs than in conventional FAs (e.g., n=2.7 for IT-4F and n=2.2 for PC₇₁BM). Meanwhile, in terms of the $\varepsilon_{\rm r}$ of acceptors, Zhu et~al. performed a computational study using density functional theory (DFT) and found that planar and rigid A–D–A structures have a higher α (e.g., $\alpha=247.5$ Å 3 , $\varepsilon_{\rm r}=5.11$ for IT-4F, and $\alpha=114.5$ Å 3 and $\varepsilon_{\rm r}=3.83$ for PC₇₁BM) and a smaller $E_{\rm b}$ (e.g., $E_{\rm b}=0.35$ and 0.90, 0.63 for IT-4F, PC₇₁BM, SF-PDI2, respectively) than bulky or spherical structures. In addition, grazing-incidence wide-angle X-ray scattering measurement has been used to reveal that the $R_{\rm DA}$ between the polymer donor and the NFA is close enough for effective intermolecular reorganization (e.g., $R_{\rm DA}=3.61$ Å for PM6:Y6). In

The long exciton lifetime (τ) also plays a critical role in improving the exciton-splitting efficiency in low ΔE_{CT} systems (Fig. 5b). Here, Classen et al. examined the lifetime and efficiency of exciton splitting using polymer donor:NFA blends with a ΔE_{HOMO} of 0-0.3 eV, with the NFA-based OPVs exhibiting slow exciton-splitting lifetimes ($\tau_{\text{splitting}} > 20 \text{ ps}$) and high excitonsplitting efficiencies ($\eta_{\text{splitting}} > 90\%$) owing to the long τ of NFAs (305.3, 561.5, 898.3, and 1016 ps for ITIC, o-IDTBR, EH-IDTBR, and Y6, respectively). 139 This demonstrates that NFAs with a long τ allow for efficient exciton splitting even with a negligible driving force (i.e., $\Delta E_{\rm CT}$ < 0.2 eV). In practice, NFAbased OPVs have recently been reported to exhibit high PCEs even with a negligible $\Delta E_{\rm CT}$ or $\Delta E_{
m HOMO}$. For example, the PM6:Y11-based OPV exhibits a PCE of 16.54% despite the $\Delta E_{\rm CT}$ of 0 eV,82 while the PTQ11:TPT10-based OPV exhibits a PCE of 16.32% even at a ΔE_{HOMO} of 0 eV.¹⁴⁰

4.2.3. CT state recombination. The small wave-function overlap between the $\mathrm{HOMO_D}$ and the $\mathrm{LUMO_A}$ significantly reduces the oscillator strength of CT excitons, resulting in a comparatively slower $k_{\rm r}$ than $k_{\rm nr}$. ¹³² In other words, CT excitons are decayed primarily through non-radiative recombination (*i.e.*, low EQE_{EL}). The difference in CT oscillator strength between FA-and NFA-based OPVs becomes evident in terms of and EQE_{EL}. Indeed, NFA-based OPVs exhibit a lower $\Delta V_{\rm OC}^{\rm non-rad}$ (<0.35 V) and

a higher EQE $_{\rm EL}$ ($\approx 10^{-4}$) than FA-based OPVs ($\Delta V_{\rm OC}^{\rm non-rad} = 0.35$ –0.46 V, EQE $_{\rm EL} \approx 10^{-6}$ –10 $^{-8}$), indicating that NFAs considerably suppress the non-radiative recombination in blend devices.¹⁴¹

In addition to lowering the $\lambda_{\rm I}$ and $\lambda_{\rm O}$ (Fig. 5c), ^{129,134} increasing the $E_{\rm CT}$ level (i.e., decreasing the $\Delta E_{\rm CT}$) can reduce the $k_{\rm nr}$ (i.e., a smaller $\Delta V_{\mathrm{OC}}^{\mathrm{non-rad}}$) because of the smaller wave-function overlap between the CT and the ground state (S₀) (Fig. 5d).¹³² Here, Benduhn et al. reported a linear regression with a slope of \approx -0.2 V eV⁻¹ between $\Delta V_{\rm OC}^{\rm non-rad}$ and $E_{\rm CT}$, ¹³² while Classen *et al.* reported a sharp decrease in $\Delta V_{\rm OC}^{\rm non-rad}$ with a slope of ≈ -0.6 V eV^{-1} at a ΔE_{HOMO} of less than 0.2 eV.¹³⁹ Eisner et al. proposed a three-state model in which a small ΔE_{CT} enables electronic coupling (hybridization) between the S₁ and the CT state to enhance the oscillator strength from CT to So. 141 As shown in Fig. 5e, the $\Delta V_{\rm OC}^{\rm non-rad}$ decreases with an increase in hybridization at a given $\Delta E_{\rm CT}$. Consequently, the $k_{\rm nr}$ slows down as the $\Delta E_{\rm CT}$ decreases in the absence of hybridization, while the k_r remains almost constant (Fig. 5f). However, the hybridization affects the $k_{\rm r}$ much more than the $k_{\rm nr}$, thus increasing the oscillator strength of the CT exciton in low- ΔE_{CT} systems (i.e., higher EQE_{EL}). For example, the PM6:Y11 device has a ΔE_{CT} of 0 eV and exhibits a higher EQE_{EL} (EQE_{EL} $\approx 1.4 \times 10^{-3}$, $\Delta V_{\rm OC}^{\rm non-rad} = 0.17$ V) than conventional high-performance FA-based OPVs. Moreover, the overall $V_{\rm loss}$ of the PM6:Y11 device is 0.43-0.51 V, which is very close to that of c-Si solar cells (0.38 V).82

4.3. Charge transport

4.3.1. Charge transport physics. The charge transport of free charge carriers (*i.e.*, holes and electrons) separated from the excitons is an important factor in determining the charge collection efficiency and is highly related to the $J_{\rm SC}$ and FF parameters. In addition, efficient and balanced charge transport in the blend film, along with suppressed non-geminated recombination, is desirable in terms of improving the charge collection efficiency. However, most organic semiconductors contain a large amount of disordered regions (*i.e.*, amorphous domains), 85,93,143 generating energetic disorders that limit the efficient charge transport. On the other hand, the structural features of NFAs enable efficient electron transport through an increased electron transfer integral ($|J_e|$) or a reduced energetic disorder, and they showed well-balanced charge transport with polymer donor materials.

4.3.2. A–D–A-type non-fullerene acceptors. The planar and rigid structure of A–D–A-type NFAs can provide close intermolecular packing (3–4 Å) and can enhance the structural resilience with low energetic disorders. While the close packing between adjacent molecules is essential for efficient charge transport, effective electronic coupling should be considered because of the different wave-function shapes along the molecular backbone. In other words, an optimal wave-function overlap (*i.e.*, HOMO and HOMO-1 for hole transport, LUMO and LUMO+1 for electron transport) enables effective electronic coupling, ¹⁰³ thus increasing the |J| of NFAs. In practice, a large displacement between the LUMO and the LUMO+1 in NFAs can result in a lower $|J_e|$ than in FAs (*e.g.*, 11.4 meV for ITIC⁹⁸ and 50 meV for PC₆₁BM¹⁴⁴).

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Aldrich et al. studied the change in μ_e with a number of F substituents at the end-groups of A-D-A-type NFAs (ITIC, ITIC-4F, and ITIC-6F).98 Here, the DFT calculation revealed that all NFAs have similar electron delocalization but that the LUMO and LUMO+1 are predominantly localized on the end-groups. In the single-crystal analysis, the ITIC and ITIC-6F were found to exhibit face-to-face π - π stacking between the end-groups (\approx 3.4 Å for ITIC and 3.95, 3.28 Å for ITIC-6F), while the ITIC-4F had a coexisting packing of face-to-face and edge-to-face stacking (3.35 Å) (Fig. 6a). Meanwhile, in addition to the π - π stacking, lone-pair $\cdots\pi$ interactions were observed in the ITIC-4F (S $\cdots\pi$) and ITIC-6F (CN $\cdots\pi$), contributing to closer intermolecular packing distances (3.21 Å for ITIC-4F and 3.16 Å for ITIC-6F). Finally, the $|I_e|$ calculated from the crystal dimers was 11.4, 17.1 and 56.8 meV for the ITIC, ITIC-4F and ITIC-6F, respectively, with the ITIC-6F consequently exhibiting a higher μ_e (5.7 imes 10 $^{-4}$ cm 2 V $^{-1}$ s $^{-1}$) than the other two NFAs (3.1 imes 10 $^{-4}$ and 5.1 \times 10⁻⁴ cm² V⁻¹ s⁻¹ for ITIC and ITIC-4F, respectively).

4.3.3. A-D-A'-D-A-type non-fullerene acceptors. The A-D-A'-D-A-type NFA with a curvature structure (*e.g.*, Y6 analogs) has more intermolecular packing modes than A-D-A-type NFAs. ^{103,104} As noted above, the A-D-A-type NFAs mainly adopt end-group stacking due to the bulky side chains on the core unit. In contrast, Y6 analogs can form multiple packings between the end-groups as well as core units due to the curvature structure and the less bulky alkyl chains (*e.g.*, linear alkyl chain) on the core unit (Fig. 6b).

Zhang et al. identified the multiple packings in a Y6 single crystal and obtained the $|I_e|$ from the Y6 dimer packings. ¹⁰³ Here, the Y6 had a longer intermolecular distance ($\approx 3.5 \text{ Å}$) than had the ITIC-based NFAs but exhibited a larger $|J_e|$ (81 meV) and $\mu_{\rm e}$ (1.8 \times 10⁻⁴ cm² V⁻¹ s⁻¹) because of its multiple packing structure. In addition, the core unit packing was found to enhance the overlap between the HOMO and HOMO-1, exhibiting high hole transfer integral ($|I_h|$) (74 meV) and hole mobility (μ_h) (5.6 \times 10⁻⁴ cm² V⁻¹ s⁻¹). These features enable the ambipolar charge transport of Y6, which is beneficial for a balanced charge transport in polymer donor:NFA blends. Elsewhere, Hamada et al. examined the μ_e and μ_h of PBDB-T based blends, 145 where the PBDB-T:NFA blends exhibited a more balanced charge transport than the PBDB-T:PC₇₁BM blend (μ_h / $\mu_{\rm e} = 0.057, 0.95, 1.14$ for PBDB-T:PC₇₁BM, PBDB-T:Y6 and PBDB-T:ITIC, respectively).

4.3.4. Energetic disorder. The charge transport of organic semiconductors is strongly governed by the hopping mechanism, ¹⁴⁶ meaning a large degree of energetic disorder increases the trap density in the amorphous regions, thus boosting the non-geminate recombination. The total energetic disorder (σ) includes dynamic (σ _D) and static energetic disorder (σ _S) and is expressed as $\sigma = \sigma_{\rm D}^{\ 2} + \sigma_{\rm S}^{\ 2}$, ¹⁴⁷ while the planar and rigid backbone structure (*e.g.*, IDT-based cores) enhances the structural resilience and constructs interconnected aggregates (or small crystallites) with a short-range order. ^{148,149} Such a morphology provides efficient charge transport with a narrow trap

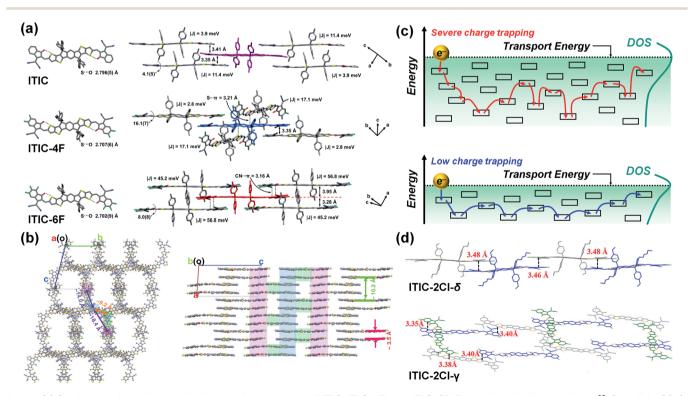


Fig. 6 (a) Single crystal and intermolecular packing structure of ITIC, ITIC-4F, and ITIC-6F. Reproduced with permission. ⁹⁸ Copyright 2019, American Chemical Society. (b) Crystal packing structure of Y6. Reproduced with permission. ¹⁰³ Copyright 2020, Springer Nature. (c) Schematic illustration of electron transport for organic semiconductors governed by hopping mechanism (top: large DOS, bottom: small DOS). (d) Molecular packing structure of ITIC-2Cl- δ (top) and ITIC-2Cl- γ (bottom). Reproduced with permission. ¹⁵² Copyright 2019, Elsevier.

distribution *via* continuous electrical connections between the aggregates (Fig. 6c).

Kupgan *et al.* quantified the MD and DFT approaches and found that the NFA had a lower σ than the FA through a combination of molecular dynamics ($\sigma=54,\,52,\,77$ meV for FNIC1, FNIC2, PC₇₁BM, respectively). ^{147,150} The low σ values of NFAs are largely due to the significant decrease in $\sigma_{\rm S}$ (24, 25, and 46 meV for FNIC1, FNIC2, and PC₇₁BM, respectively), indicating that coplanar and rigid backbone structures are more effective in reducing $\sigma_{\rm S}$ than are spherical structures.

Modulating the intermolecular interaction of the NFA can further facilitate cross-stacking, constructing an interconnected network structure that provides 3D charge transport pathways in OPV blends. ^{93,151} Lai *et al.* introduced Cl atoms to the delta (ITIC-2Cl- δ) or gamma (ITIC-2Cl- γ) position of ITIC endgroups. ¹⁵² Here, the ITIC-2Cl- γ crystal exhibited an interconnected network structure containing both linear- and cross-stackings, while the ITIC-2Cl- δ crystal mainly adopted a linear stacked structure (Fig. 6d). Meanwhile, when blended with PBDB-TF, the PBDB-TF:ITIC-2Cl- γ exhibited a higher μ_e (2.6 ×

 $10^{-4}~{\rm cm^2~V^{-1}~s^{-1}}$) than did the PBDB-TF:ITIC-2Cl- δ ($\mu_e=1.2\times10^{-4}~{\rm cm^2~V^{-1}~s^{-1}}$). Elsewhere, Zhang *et al.* investigated the energetic disorder of representative polymer-based blends by measuring the Urbach energy ($E_{\rm U}$), which represents the trap distribution. Here, the polymer donor:FA blends exhibited a higher $E_{\rm U}$ (*e.g.*, $E_{\rm U}=36.0$ meV for PffBT4T-2OD:PC₇₁BM) than did the polymer donor:NFA blends (*e.g.*, $E_{\rm U}=34.4$ and 22.4 meV for PBDB-T:ITIC and PM6:Y18, respectively). This result demonstrated that the interconnected structure of Y18 efficiently reduces the trap density of OPV blends.

4.4. Triplet-exciton harvesting

4.4.1. Role of triplet excitons. The lowest triplet state (T_1) is typically located approximately 0.6–1 eV below the S_1 and can present a loss source of photo-excited excitons. ^{153,154} However, triplet excitons have a long L_D of hundreds of nanometers because of their long $\tau_{\rm exc}$, providing sufficient time for CT excitons to separate into free charge carriers. ^{49,154–157} As such, triplet materials have the latent capability to further improve device performances. To exploit triplet excitons efficiently, the

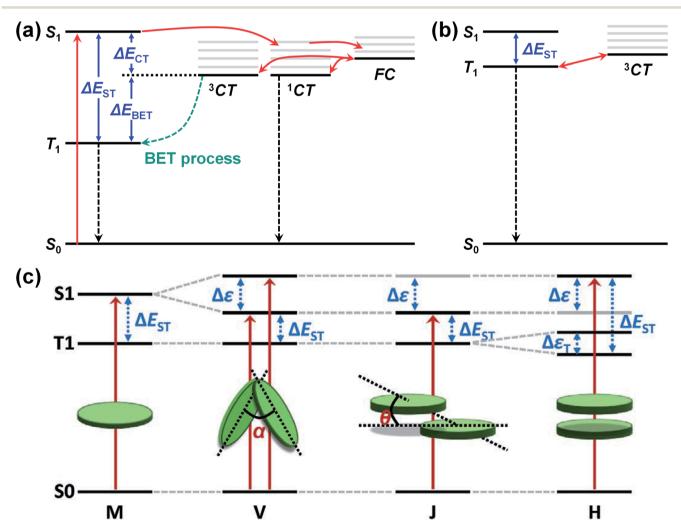


Fig. 7 (a) Schematic illustration of triplet-recombination through back electron transfer (BET) process. (b) Energy diagram with small ΔE_{CT} , ΔE_{ST} , and ΔE_{BET} . (c) Schematic energy diagram of S_1 and T_1 splitting according to molecular packing modes (V-type, J-type, and H-type molecular packing structures). Reproduced with permission. Copyright 2020, WILEY-VCH.

energy difference between the S₁ and T₁ (*i.e.*, $\Delta E_{\rm ST} = E_{\rm S_1} - E_{\rm T_1}$) and the $\Delta E_{\rm CT}$ should be as small as possible to prevent an energetically favored back electron transfer (BET) from 3 CT to T₁ of the donor or acceptor (Fig. 7a). The BET process causes triplet recombination through triplet–triplet annihilation and is accelerated as the energy difference between the $E_{\rm CT}$ and the $E_{\rm T_1}$ (*i.e.*, $\Delta E_{\rm BET} = |E_{\rm CT} - E_{\rm T_1}|$) increases. $^{153,158-160}$ Energy level engineering that increases the T₁ or moves it closer to 3 CT has demonstrated the feasibility of suppressing the BET process (Fig. 7b). 157,161

4.4.2. NFAs with the heavy atom effect. The introduction of heavy atoms (e.g., iridium [Ir] or platinum [Pt]) into π -conjugated molecules enhances the spin–orbit coupling between the S_1 and the T_1 , generating triplet excitons through the intersystem crossing (ISC). ¹⁶² Such triplet excitons are easily converted to ³CT excitons when the T_1 is higher than the ³CT. To date, polymer donors containing Ir or Pt metals (e.g., poly-DPP-Ph-Pt and poly-DPP-Th-Pt) have been the focus of most reports but have exhibited low device performances because of the poor blend morphology with the acceptor materials (i.e., large-scale phase separation). ^{155,163}

Meanwhile, Yang *et al.* reported a PDI-based triplet acceptor in which tellurophene was fused with two PDI units (BFPTP). The triplet excitons of the BFPTP were confirmed *via* the photoluminescence (PL) emission with a long lifetime of 24.41 ms at 77 K. The energy level of the T_1 (E_{T_1}) of the BFPTP was 1.50 eV, which is higher than the E_{CT} of PBDB-T:BFPTP (1.45 eV), indicating that triplet excitons can be converted into 3 CT excitons. The PBDB-T/BFPTP bilayer device demonstrated that the BFPTP had a long L_D of 34 nm (similar to the L_D of triplet FAs), and, as a result, the PBDB-T:BFPTP-based OPV exhibited a PCE of 7.52%, which was a meaningful result that demonstrated, for the first time, the feasibility of utilizing a triplet NFA.

4.4.3. NFAs with a small ΔE_{ST} . A small ΔE_{ST} (*i.e.*, large spin–orbit coupling) is beneficial to harvesting triplet excitons without heavy atoms, which can be observed in highly twisted structures between the electron-rich and electron-deficient units. However, the highly twisted structure of NFAs has drawbacks in terms of inefficient light harvesting and charge transport. However,

Among the NFA molecules, Y6-derivatives have a slightly twisted structure owing to the sp²-hybridization of the N atoms in the main backbone and are good candidates for triplet acceptors. Oin *et al.* reported two triplet acceptors, both analogs of Y6 (H1 and H2), observed long PL decays on the μ s scale in both acceptors (8.15 μ s for H1 and 7.66 μ s for H2 at 77 K). The two NFAs exhibited a relatively small $\Delta E_{\rm ST}$ (\approx 0.35 eV) and had an $E_{\rm T_1}$ (\approx 1.07 eV) close to the $E_{\rm CT}$ (\approx 1.37 eV) of blend films employing PBDB-T as a polymer donor. Meanwhile, the transient absorption decay was 65 ns for the PBDB-T:H1 and 35 ns for the PBDB-T:H2, which was much longer than the S1 decay of each component. The existence of triplet excitons in the PBDB-T:H1 and PBDB-T:H2 devices was confirmed *via* magneto-photocurrent measurement, with both devices exhibiting a high PCE of over 14%.

In addition, the ΔE_{ST} can be controlled *via* the molecular packing mode. In V-type or J-type packing modes (*i.e.*, small

intermolecular overlap), the T₁ splitting is negligible, while the S₁ splitting is significant because of the small intermolecular overlap. As shown in Fig. 7c, this splitting difference can reduce the $\Delta E_{\rm ST}$. In contrast, an H-type packing mode (i.e., large intermolecular overlap) can increase the ΔE_{ST} since both the S₁ and the T₁ will be significantly split. 169,170 Elsewhere, Han et al. conducted a theoretical study using time-dependent DFT (TD-DFT) calculations in combination with MD simulations and found that the $\Delta E_{\rm ST}$ could be reduced by end-group π - π stacking in A-D-A- or A-D-A'-D-A-type NFAs.153 The calculated $\Delta E_{\rm ST}$ of the J-type dimer for IT-4F and Y6 were 0.35 and 0.32 eV, respectively, with the two V-type dimers possessing a similar $\Delta E_{\rm ST}$ to the J-type dimers. Compared with the $\Delta E_{\rm ST}$ of the monomers (0.44 eV for IT-4F, 0.42 eV for Y6), the J-type and Vtype dimers exhibited a decrease in ΔE_{ST} of around 0.1 eV because of the end-group π - π stacking. Meanwhile, because of the reduced $\Delta E_{\rm ST}$, the $\Delta E_{\rm BET}$ for PM6:IT-4F and PM6:Y6 was calculated to be 0.13 and 0.23 eV, respectively, indicating that T₁ excitons can assist the regeneration of free charge carriers. Finally, the transfer rate from T_1 to $^3CT(k_{T_1 \to CT})$ for both blends was estimated to be 10^7-10^9 s⁻¹, while the rate of triplet recombination $(k_{\rm T_1 \to S_0})$ was calculated to be 4-7 \times 10³ s⁻¹, around 4–6 orders lower than the $k_{T_1 \to CT}$.

4.5. Blend morphology

4.5.1. Blend miscibility and the Flory–Huggins parameter. The D:A blend films form a three-phase morphology (pure D, pure A, and intermixed phase), with its composition determined by the degree of mixing between the D and the A.^{171–173} The blend morphology is highly related to the FF and stability of the OPV device, with the well-mixed blend morphology providing efficient charge transport while suppressing the charge recombination.^{174,175} Therefore, understanding the thermodynamics and kinetics of the morphology formation is important for the rational design of blend films.

The phase behavior of the amorphous mixed phase is controlled by the molecular interaction of the D and A. Here, the Flory–Huggins model has been widely used to quantify the degree of mixing between the blend components and has been extended quantitatively to describe the thermodynamic behavior of D:A blends. ^{173,176,177} The change in the Gibbs free energy of mixing ($\Delta G_{\rm mix}$) in a polymer-containing blend can be expressed by the following equation: ¹⁷⁷

$$\Delta G_{\text{mix}} = kT \left(\frac{\mathcal{O}_1}{N_1} \ln \mathcal{O}_1 + \frac{\mathcal{O}_2}{N_2} \ln \mathcal{O}_2 + \chi \mathcal{O}_1 \mathcal{O}_2 \right)$$
(13)

where \emptyset and N are the volume fraction of the components and the effective molecular sizes of the polymers (e.g., molecular weight or degree of polymerization), respectively, while χ is the Flory–Huggins interaction parameter that quantifies the enthalpic interaction between the mixed components, where the lower the χ value, the higher the degree of molecular mixing. To date, differential scanning calorimetry (DSC),¹⁷⁸ contact angle,¹⁷⁹ solubility parameter,^{180,181} and time-of-flight secondary ion mass spectrometry (TOF-SIMS)¹⁷⁹ analyses have been used for determining χ .

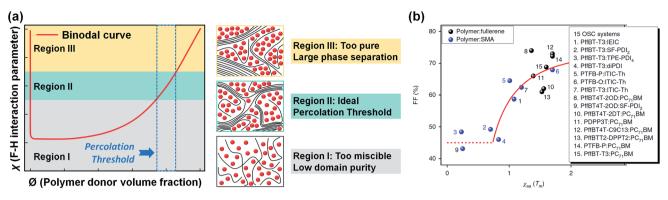


Fig. 8 (a) Schematic illustration of three regions in the binodal curve of the χ – \emptyset phase diagram; low χ (region II), medium χ (region III), and high χ (region III), respectively. (b) χ parameter estimated from DSC and its relation to FF. Reproduced with permission.¹⁷⁴ Copyright 2018, Springer Nature.

The mixed phase can be divided into three regions in the binodal curve of the χ – \emptyset phase diagram (Fig. 8a). ^{174,182} Here, the blend in the low χ region is too miscible and has a low domain purity, while large phase separation occurs when the domains are too pure (*i.e.*, high χ region). These two cases result in performance degradation due to inefficient photocurrent generation paths (*e.g.*, increased charge recombination and low charge collection efficiency). The ideal χ with a binary composition close to the percolation threshold can lead to optimal amorphous miscibility and stable morphology in a thermodynamic equilibrium state; however, most OPV blends exhibit a higher or lower χ that deviates from the ideal χ region.

4.5.2. Blend morphology, device FF and stability. Since the χ plays an important role in morphology formation, the miscibility-device function relationship is of great interest in terms of manipulating a blend composition to determine the optimal χ . Here, Ade *et al.* developed a measurement technique to accurately determine the temperature dependence of the χ (*i.e.*, $\chi[T]$) for representative OPV blends and established a quantitative model of the relationship between the domain purity of the mixed phase and the device FF, which can be expressed by the following equation: 174

$$FF \propto \sigma = \sqrt{ISI} \propto \sqrt{(\mathcal{O}_0 - \mathcal{O}_1)(\mathcal{O}_2 - \mathcal{O}_0)}$$
 (14)

where ISI is the integrated scattering intensity of the resonant soft X-ray scattering (R-SoXs), with the square root of the ISI representing the relative domain purity (σ) .¹⁹² This model was experimentally verified using 15 types of blend system (*e.g.*, polymer donor:PC₇₁BM and NFA), which indicated a constant-kink-saturation relationship between the χ and the device FF, where the larger the χ , the higher the σ (*i.e.*, stronger phase separation), and, thus, the higher the device FF.¹⁷⁴ In addition, the majority of polymer donor:PC₇₁BM blends exhibit a larger χ and a higher device FF (1.3 < χ < 1.7, 61% < FF < 74%) than do polymer donor:NFA blends (0.23 < χ < 1.01, 46% < FF < 65%) (Fig. 8b and Table 2).

Nevertheless, most of the FA-based OPVs suffer from the so-called "burn-in loss" issue, which causes an initial loss of up to 30–40% of the PCE.¹⁹³ These burn-in losses originate from the photoinduced degradation of FAs (*i.e.*, dimerization) and from

crystallization, leading to a macroscopic phase separation of the blend film. 194,195 Li *et al.* investigated the de-mixing in polymer donor: $PC_{71}BM$ blends under aging conditions (5 days). 196 Here, using grazing-incidence small-angle X-ray scattering, the $PC_{71}BM$ domain size was found to have increased from 43 nm (the initial blend film) to 78 nm (the aged blend film; 80% increase). As the size of pure the $PC_{71}BM$ domains increased in the aged sample, the volume fraction and size distribution of the $PC_{71}BM$ domains also increased. In other words, the growth of larger clusters and phase separation occurred in the polymer donor: $PC_{71}BM$ blend under the aging condition when the $PC_{71}BM$ molecules diffused out of the amorphous mixed phases.

On the other hand, it has been reported that NFAs suppress the burn-in loss to light and heat owing to their higher chemical stability and miscibility compared with FAS. $^{86-88,197}$ Zhu *et al.* characterized the change in the IEICO-4F domain size in the amorphous mixed phase (PTB7-Th:IEICO-4F) under aging conditions (90 days), as measured *via* R-SoXs. 86 The size of the IEICO-4F domains increased from 38 nm (initial blend film) to 43 nm (aged blend film; 13% increase). This indicates that the NFA-based blend system has a more stable film morphology than the FA-based blend system. Furthermore, Du *et al.* reported a promising long-term stability system of NFA blend films with an extrapolated T_{80} lifetime (80% of the initial PCE) of over 11 000 h under one-sun illumination. 197

4.5.3. Molecular designs for morphology control. Various molecular design strategies for controlling the molecular miscibility have been reported in relation to polymer–NFA domain size, purity, and device FF.¹⁷³ In the molecular design of polymer donors, an approach involving an increase in the rigidity of the polymer donor has proven to be effective for the nanoscale-phase separation in blend films without excessive intermixing with NFAs (*i.e.*, higher χ). Here, Li *et al.* investigated the impact of molecular packing on the blend miscibility (polymer donor:IT-4F) by adjusting the alkyl chains of polymer donors (*n*-octyl for P1, *n*-decyl for P2, and 3,7-dimethyloctyl for P3).¹⁸⁹ The P2 polymer with a long linear alkyl chain exhibited lower blend miscibility ($\chi = 0.25$ K, measured in terms of surface energy) than did the other two blends ($\chi = 0.15$ K for P1:IT-4F, $\chi = 0.19$ K for P3:IT-4F) owing to the close

Table 2 OPV performance with χ and ISI value for polymer donor:FA and polymer donor:NFA

Acceptor	Donor	$V_{ m OC}\left[m V ight]$	$J_{ m SC}[{ m mA~cm}^{-2}]$	FF [%]	PCE [%]	χ_{aa}	ISI	Ref.
FAs								
$PC_{71}BM$	PDPP3T	0.66	15.4	66	6.6	1.39 $(T_{\rm m})^a$	1	174 and 183
$PC_{71}BM$	PTFB-P	0.81	12.9	72	7.5	$1.70 (T_{\rm m})^a$	_	174 and 184
PC ₇₁ BM	PffBT4T-2DT	0.76	16.2	62	7.6	1.56 $(T_{\rm m})^a$	_	174 and 18
$PC_{71}BM$	PffBTT2-DPPT2	0.81	17.1	61	8.6	$1.53 (T_{\rm m})^a$	_	174 and 186
$PC_{71}BM$	PffBT4T-2OD	0.77	18.4	74	10.5	1.36 $(T_{\rm m})^a$	1	22 and 174
PC ₇₁ BM	PffBT-T3	0.82	18.9	69	10.7	$1.60 (T_{\rm m})^a$	_	174 and 187
PC ₇₁ BM	$PffBT4T\text{-}C_9C_{13}$	0.78	19.8	73	11.7	$1.70 (T_{\rm m})^a$	1	23 and 174
PDI-based N	FAs							
SF-PDI2	PffBT4T-2OD	0.97	6.9	43	2.9	$0.25 (T_{\rm m})^a$	_	174
diPDI	PffBT-T3	0.86	12.8	46	5.1	$0.83 (T_{\rm m})^a$	0.56	174
TPE-PDI4	PffBT-T3	1.02	11.5	48	5.7	$0.23 (T_{\rm m})^a$	0.32	174
SF-PDI2	PffBT-T3	1.03	12.3	49	6.2	$0.70 (T_{\rm m})^a$	0.52	174
IDT-based N	FAs							
IEIC	PffBT-T3	1.04	12.6	59	7.7	$1.08 \ (T_{ m m})^a$	0.83	174
ITIC-Th	PTFB-P	0.92	15.5	65	9.2	$1.01 (T_{\rm m})^a$	0.91	174
ITIC-Th	PTFB-O	0.92	17.1	68	10.9	$1.70 (T_{\rm m})^a$	1	174
IT-DM	PBDB-T	0.96	16.3	69	11.3	2.0 $(HSP)^{b}$	0.83	188
IT-M	PBDB-T	0.94	17.3	71	12.1	$2.7 (HSP)^b$	0.97	188
IT-4F	P1	0.90	20.1	64	11.5	$0.15~\mathrm{K}^c$	_	189
IT-4F	P2	0.90	20.7	76	14.2	0.25 K^c	_	189
IT-4F	P3	0.90	20.3	61	11.2	0.19 K ^c	_	189
Y6-based NF	As							
Y6	PM6	0.86	25.5	72	15.8	$0.20~\mathrm{K}^c$	_	190
Y6	PM1	0.87	25.9	78	17.6	$0.26~\mathrm{K}^c$	_	190
BTP-4Cl	РЗНТ	0.50	5.16	39	1.01	$2.52 (HSP)^{b}$	_	191
ZY-4Cl	РЗНТ	0.88	16.5	65	9.46	2.56 (HSP) ^b	_	191

^a The value obtained from DSC. ^b HSP. ^c Contact angle measurement.

intermolecular packing. The P2:IT-4F device also exhibited an FF of 70% and maintained 80% of the initial PCE for 2000 min under one-sun illumination. Elsewhere, Wu et al. synthesized a PM6-based random copolymer (PM1) containing 20 mol% thiophene-thiazolothiazole, a highly planar moiety. 190 Here, the incorporation of the planar moiety increased the polymer rigidity and reduced the blend miscibility ($\chi = 0.26$ K for PM1:Y6, $\chi = 0.20$ K for PM6:Y6). Meanwhile, a more obvious phase separation with an interpenetrating network morphology was observed in the PM1:Y6 blend than in the PM6:Y6 blend, with a higher FF obtained from the PM1:Y6 device (FF = 78% and 72% for PM1:Y6 and PM6:Y6, respectively).

In terms of NFA design, Li et al. extended the π -conjugation of an IDTI by replacing the phenyls with naphthyls (IDTN) to enhance the intermolecular packing.198 Here, the PBDB-TF:IDTN blend film had a much longer π - π coherence length (9.4 nm) in the out-of-plane direction than the reported PBDB-Tbased blend film (1-5 nm), 188,199 while a larger domain size was observed in the PBDB-TF:IDTN blend (65.5 nm) than in the PBDB-TF:IDTI blend, which was due to the more ordered molecular packing of IDTN. The PBDB-TF:IDTN device also exhibited an improved FF (78%) compared with the PBDB-TF:IDTI device (57%).

Chemical substitutions at the end-group of NFAs have also been reported to be effective in increasing the intermolecular interactions. Here, Yang et al. substituted the cyano groups in BTP-4Cl-12 with oxygen atoms (ZY-4Cl) and confirmed that ZY-4Cl lowered the miscibility with P3HT through the weak endo/ exothermic peak in the DSC curve (no peak in P3HT:BTP-4Cl-12).¹⁹¹ The χ values obtained from the Hansen solubility parameters (HSPs) were 2.52 and 2.56 for P3HT:BTP-4Cl-12 and P3HT:ZY-4Cl, respectively, indicating the enhanced phase separation in P3HT:ZY-4Cl. Meanwhile, the P3HT:ZY-4Cl blend morphology contributed a higher efficient exciton probability (81% for P3HT:ZY-4Cl, 34% for P3HT:BTP-4Cl-12) and an improved device FF of 65% (FF = 39% in the P3HT:BTP-4Cl-12 device).

Summary and outlook

Largely because of the advances in NFA material design, NFAbased OPVs have demonstrated significant improvements in device performance. Specifically, NFA-based OPVs have achieved remarkable increases in the $J_{\rm SC}$ and $V_{\rm OC}$ parameters, which far exceed those of FA-based OPVs. This comprehensive review of the studies on NFAs conducted over the past decade revealed the optimal photophysical, electrical, and morphological characteristics for high-performance OPVs. The distinctive physical features and the current understandings in the field can be summarized as follows:

- (1) Light harvesting is the key factor in determining the $J_{\rm SC}$. Overall, NFAs have smaller $E_{\rm g}$ and larger α values compared with FAs, which enhances the photon absorption. Meanwhile, NFA-based OPVs with an $E_{\rm g}$ of 1.2–1.6 eV achieve a high $J_{\rm SC}$ of >20 mA cm⁻² by covering a wide region (400–1100 nm) through complementary light absorption with the polymer donors. In addition, the long $L_{\rm D}$ of the NFA offers the feasibility of photocurrent generation even in thick photoactive layers (*i.e.*, almost equal to a micrometer scale).
- (2) The CT state of a blend system promotes exciton dissociation, but a large $\Delta E_{\rm CT}$ generates substantial $V_{\rm loss}$. Here, NFAs with a low $\lambda_{\rm I}$ and $\lambda_{\rm O}$ provide effective charge-separation, even in blend systems with a small $\Delta E_{\rm CT}$ (<0.2 eV). In addition, the small $\Delta E_{\rm CT}$ of NFA-based blends entails a decrease in $\Delta V^{\rm non-rad}_{\rm OC}$ through the hybridization between the S₁ and CT states in the blends, efficiently lowering the $V_{\rm loss}$ (<0.8 V) compared with that in FA-based blends (0.6–1.2 V).
- (3) Overall, NFAs effectively improve the |J| through endgroup π - π stacking (*i.e.*, A-D-A-type NFAs) or multiple stacking (*i.e.*, A-D-A'-D-A-type NFAs). Moreover, the planar and rigid conformation of NFAs enhances the structural resilience and facilitates close intermolecular packing, enabling efficient charge transport with a low degree of energetic disorder (*i.e.*, narrow trap distribution).
- (4) The NFAs with heavy atoms or a small $\Delta E_{\rm ST}$ can become strong candidates for photocurrent generation by harvesting triplet excitons with a long $L_{\rm D}$; however, they can also present a loss source for photo-excited excitons when the T_1 of the donor or acceptor is lower than the 3 CT (*i.e.*, the BET process). Engineering the electronic structure of NFAs to increase the T_1 or move it closer to the 3 CT effectively exploits the triplet excitons.
- (5) The majority of NFAs are more miscible with polymer donors than are FAs (*i.e.*, lower χ), while blends tend to have low domain purity. Molecular designs aimed at enhancing the intermolecular packing of the polymer donors or NFAs can increase the domain purity of the blend, thus improving the device FF. In terms of device degradation, NFA-based OPVs exhibit superior operation under photo and thermal stress due to the high chemical stability of the NFAs.

Advances in material design and device fabrications have led to significant improvements in OPV performance, often exceeding 18%, which is comparable to the panel efficiency of polycrystalline silicon PV cells, *i.e.*, 18–20% efficiency for a standard size 60-cell panel (1×1.65 m). Along with the design of NFAs, multi-faceted studies covering the development of other layer materials (*e.g.*, donor materials, electron/hole transport materials) and device fabrication (*e.g.*, optimization of device structure, film processing techniques) are still essential to maximize OPV performance. However, many challenges remain in the commercialization of OPV technology with regard to the mass production of photoactive materials and the manufacture of large-scale PV cells with long-term stability.

In terms of the materials for mass production, the current commercially available photoactive materials involve high costs ($$2000-3000~g^{-1}$), largely owing to the multi-step synthesis that consists of more than 10 steps.²⁰⁰⁻²⁰² In fact, the synthesis of

most photoactive materials involves palladium-catalyzed cross-coupling reactions (e.g., Suzuki or Stille coupling) and low-temperature reactions at $-78\,^{\circ}$ C, which is undesirable both in terms of productivity and the environment. Therefore, a short-step synthesis using precious-metal-free catalysts and moderate reaction conditions is required for the mass production of photoactive materials. Another consideration is processability through the use of green solvents, given that most photoactive materials are highly soluble in toxic, halogenated solvents (e.g., chloroform, chlorobenzene).

The large-scale fabrication of OPVs is also a challenging issue. Numerous high-performance OPVs have been demonstrated in small-area devices, mainly in the order of mm², using spin-coating methods. However, spin-coating is a non-scalable deposition method involving high material waste, and is not suitable for large-scale fabrication using a continuous deposition process.²⁰¹ Among the current methods, slot-die coating has demonstrated great potential in terms of an upscaling deposition via roll-to-roll fabrication; however, the low efficiency, small cell area, brittle substrate (e.g., ITO-coated PET sheets), and thermal evaporation are limiting a further increase in the manufacturing scale. Hence, the development of novel upscaling deposition techniques (high efficiency of >10% and large cell area of >1 cm²) and fully roll-to-roll process designs (vacuum-free process, ITO-free device architecture) is crucial for the large-scale fabrication of OPVs. Moreover, the long-term stability of the devices is an essential consideration for commercial manufacturing. Given that the performance warranty of conventional silicon solar panels is 80% of the initial performance over 25 years, a performance lifetime of >10 years is recommended for OPVs.

Aside from the material and cell fabrication perspectives, the origin of the photocurrent generation in OPVs has not yet been fully understood, largely because of the physical complexity of the organic-based blend system. Thus, advanced analytical techniques with high temporal and spatial resolutions are required to allow for clearly and accurately characterizing the physical features of OPV operations. In addition, computational studies using machine learning have recently demonstrated powerful techniques for understanding and predicting the physical properties of the relevant materials and blends while reducing both the time and the cost.^{203,204} Therefore, a combination of these two techniques is expected to provide a better understanding of the fundamentals in view of designing more efficient and stable OPVs.

Author contributions

All authors contributed to bibliographic research, discussion, writing, and revision of the article.

Conflicts of interest

There are no conflicts to declare.

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